

■ PRODUCT CHARACTERISTICS

V <sub>DSS</sub>	30V
R <sub>DS(on)</sub> Typ(@V <sub>GS</sub> =4.5V)	14mΩ
R <sub>DS(on)</sub> Typ(@V <sub>GS</sub> =10V)	7.5mΩ
I <sub>D</sub>	25A

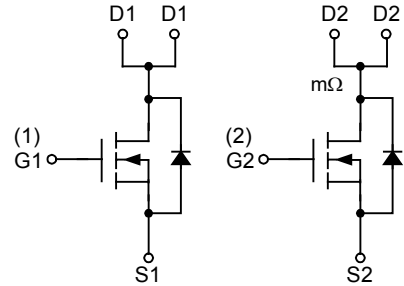
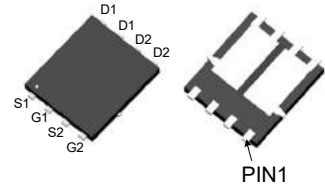
■ APPLICATIONS

DC/DC converter  
Ideal for high-frequency switching  
and synchronous rectification

■ FEATURES

Very low on-resistance R<sub>DS(on)</sub>  
Good stability and uniformity with high E<sub>AS</sub>  
Pb-free lead plating

Pin description



N+N MOSFET

■ ORDER INFORMATION

Order codes		Package	Packing
Halogen-free	Halogen		
N/A	MOT3910G	PDFN5X6	5000pieces/Reel

■ ABSOLUTE MAXIMUM RATINGS(T<sub>C</sub>=25 , unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain-source voltage	V <sub>DSS</sub>	30	V	
Gate-source voltage	V <sub>GSS</sub>	±20	V	
Drain current	T <sub>C</sub> =25℃	I <sub>D</sub>	25	A
	T <sub>C</sub> =100℃	I <sub>D</sub>	16	A
Pulsed drain current	I <sub>DM</sub>	100	A	
Avalanche energy single pulsed	E <sub>AS</sub>	36	mJ	
Power dissipation	P <sub>D</sub>	60	W	
Junction temperature	T <sub>J</sub>	+150	℃	
Storage temperature	T <sub>STG</sub>	-55~ +150	℃	

**■ ELECTRICAL CHARACTERISTICS (T<sub>C</sub>=25 , unless otherwise specified)**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off characteristics						
Drain-source breakdown voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>DS</sub> =250μA	30	-	-	V
Drain-source leakage current	I <sub>DSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V	-	-	1	μA
Gate-source leakage current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20V, V <sub>DS</sub> =0V	-	-	100	nA
On characteristics						
Gate threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>DS</sub> =250μA	1	-	2.5	V
On-state characteristics	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =25A	-	7.5	10	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =15A	-	14	19	mΩ
Forward transconductance	g <sub>FS</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =4A	10	-	-	S
Dynamic characteristics						
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> =0V, V <sub>DS</sub> =15V f=1MHz	-	1174	-	pF
Out capacitance	C <sub>oss</sub>		-	162	-	pF
Reverse transfer capacitance	C <sub>rss</sub>		-	130	-	pF
Switching characteristics						
Total gate charge	Q <sub>g</sub>	V <sub>GS</sub> =0 to 10V V <sub>DS</sub> =15V, I <sub>D</sub> =20A	-	23	-	nC
Gate-source charge	Q <sub>gs</sub>		-	4.5	-	nC
Gate-drain charge	Q <sub>gd</sub>		-	5.5	-	nC
Turn-on delay time	t <sub>d(on)</sub>	V <sub>DD</sub> =15V, I <sub>D</sub> =15A R <sub>G</sub> =3Ω, V <sub>GS</sub> =10V	-	7	-	nS
Turn-on rise time	t <sub>r</sub>		-	15	-	nS
Turn-off delay time	t <sub>d(off)</sub>		-	25	-	nS
Turn-off fall time	t <sub>f</sub>		-	6	-	nS
Source-drain diode ratings and characteristics						
Continuous diode forward current	I <sub>SD</sub>		-	-	25	A
Diode forward current	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>SD</sub> =25A	-	-	1.2	V
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> =20A	-	10	-	nS
Reverse recovery charge	Q <sub>rr</sub>	di/dt=100A/us	-	3	-	nC

■ TYPICAL CHARACTERISTICS

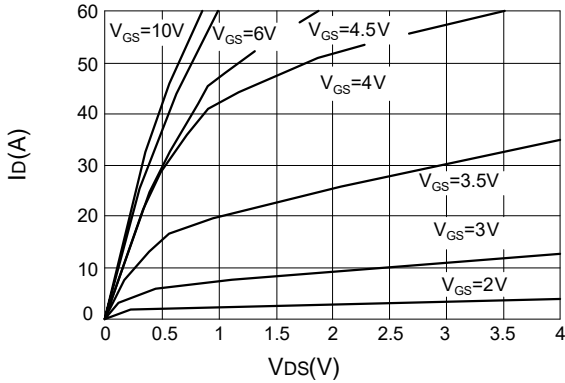


Fig.1 Output characteristic

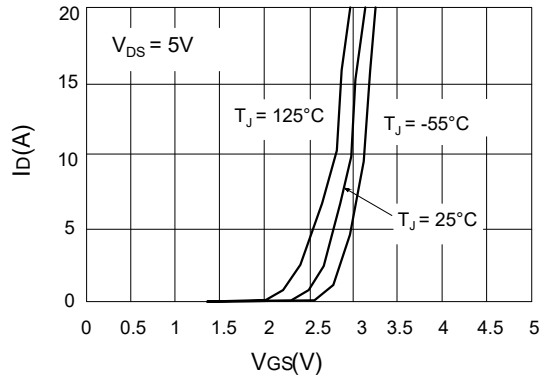


Fig.2 Transfer characteristics

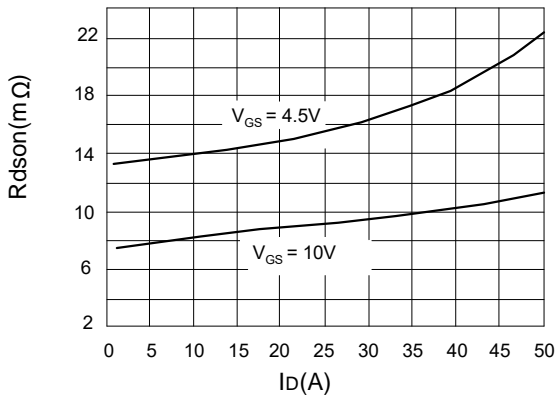


Fig.3 On-resistance vs. drain current

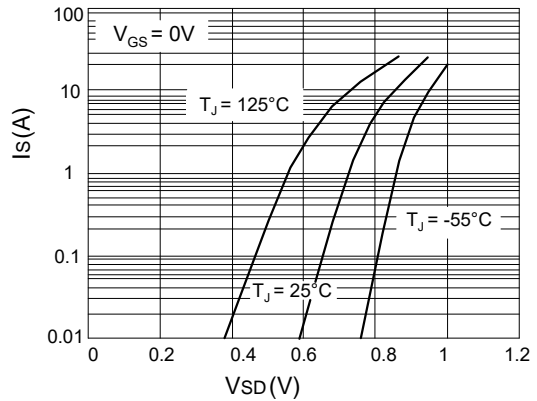


Fig.4 Body diode characteristics

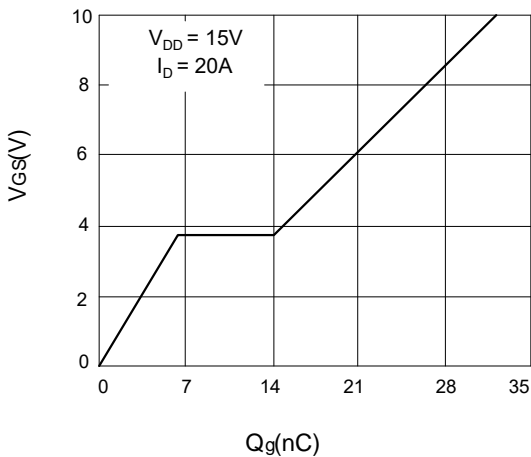


Fig.5 Gate charge characteristics

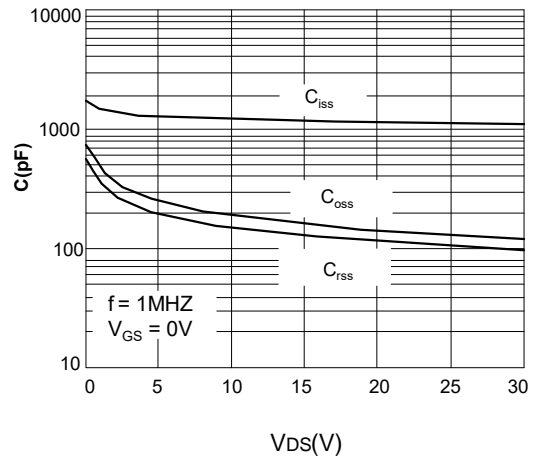


Fig.6 Capacitance characteristics

■ TYPICAL CHARACTERISTICS(Cont.)

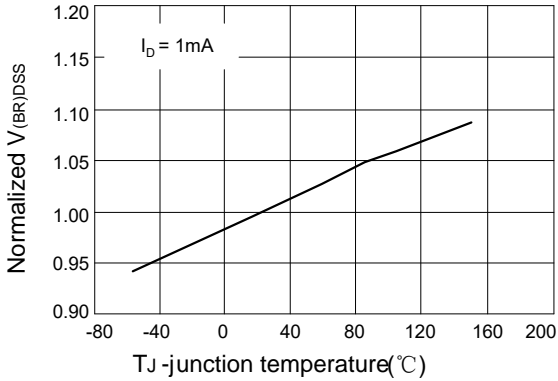


Fig.7 Normalized berkdwn voltage vs junction temperature

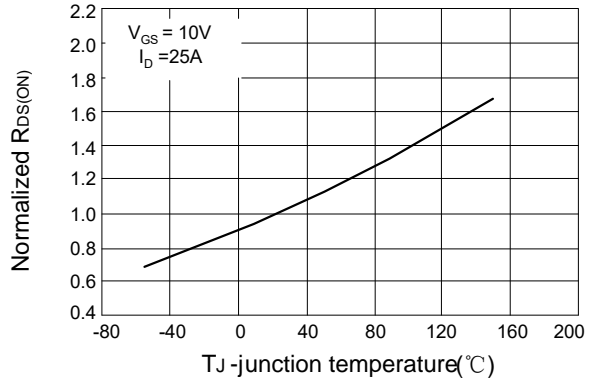


Fig.8 Normalized on resistance vs. junction temperature

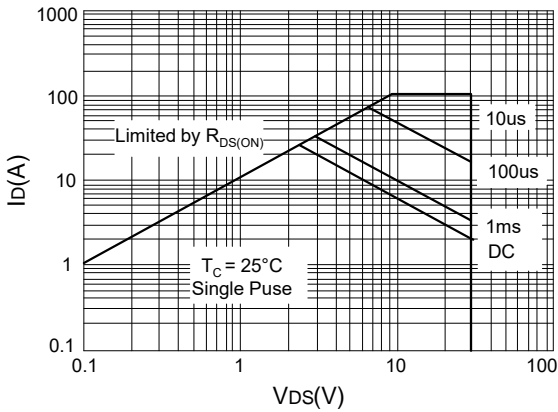


Fig.9 Maximum safe operating area

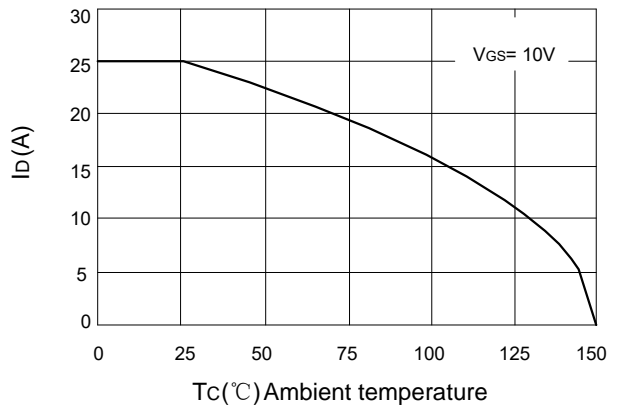


Fig.10 Maximum continuous drain current vs. ambient temperature

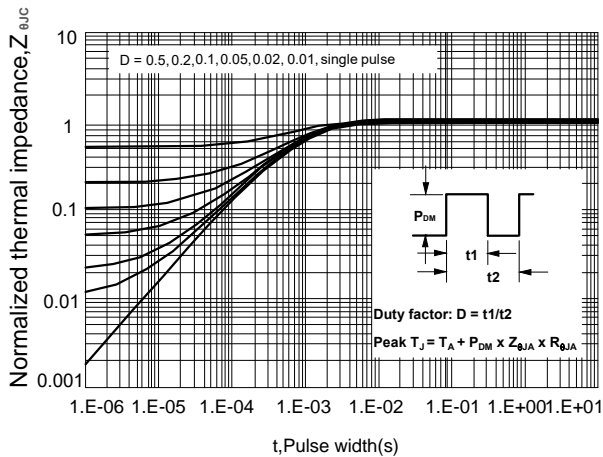


Fig.11 Normalized maximum transient thermal impedance

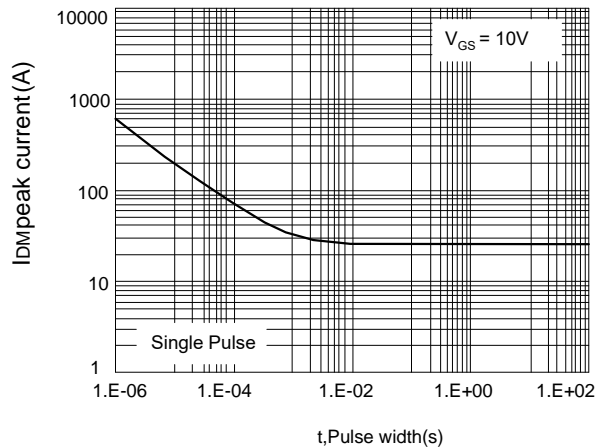
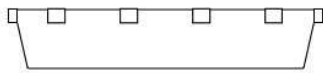
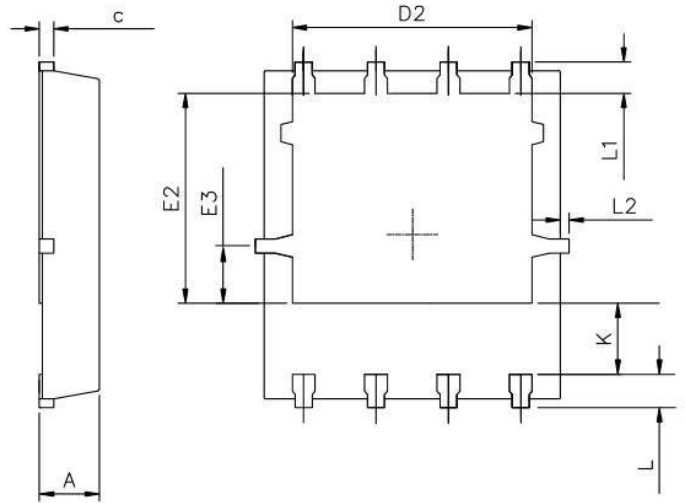
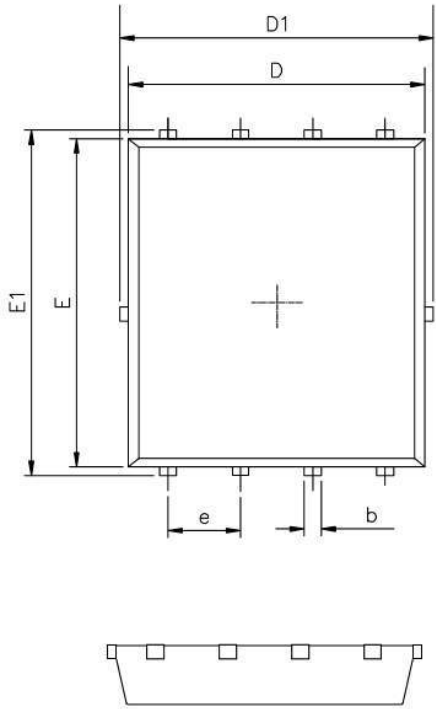
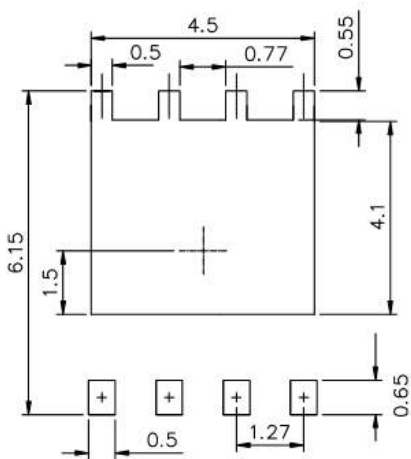


Fig.12 Peak current capacity

■ PDFN5060-8L Package Mechanical Data



RECOMMENDED LAND PATTERN



UNIT:mm

	MIN	NOM	MAX
A	0.90	1.00	1.10
b	0.25	0.35	0.50
c	0.10	0.20	0.30
D	4.80	5.00	5.30
D1	4.90	5.10	5.50
D2	3.92	4.02	4.20
E	5.65	5.75	5.85
E1	5.90	6.05	6.20
E2	3.325	3.525	3.775
E3	0.80	0.90	1.00
e		1.27	
L	0.40	0.55	0.70
L1		0.65	
L2	0.00		0.15
K	1.00	1.30	1.50